

TN08C30JPA

N and P-Channel Complementary Power MOSFET

Product Summary

- N-Channel
- V_{DS}= 30V,I_D= 8A
- $R_{DS(on)} < 31 m\Omega @V_{GS} = 10V$
- $R_{DS(on)}$ < 40m Ω @ V_{GS} = 45V
- P-Channel
- V_{DS}= -30V,I_D= -7A
- $R_{DS(on)} < 60 \text{m}\Omega @V_{GS} = -10V$
- $R_{DS(on)}$ < 87m Ω @ V_{GS} = -4.5V

Features

- Advanced Trench Technology
- 100% Avalanche Tested
- RoHS and Reach Compliant
- Halogen and Antimony Free
- Moisture Sensitivity Level 3

(Top View)

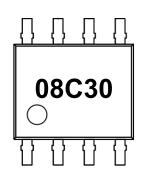
SOP-8

Pin	Description	Pin	Description
1	Source1	4	Gate2
2	Gate1	5,6	Drain2
3	Source2	7,8	Drain1

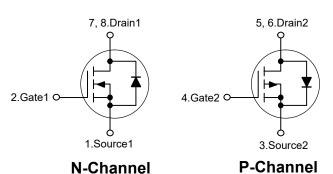
Application

Power Management

Marking Code



Schematic Diagram



Absolute Maximum Ratings

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	N-Channel P-Channel		Unit
Drain-Source Voltage	V _{DS}	30	-30	V
Gate-Source Voltage	V _{GS}	±12		V
Drain Current-Continuous	I _D	8	-7	Α
Drain Current-Pulsed Note1	I _{DM}	30 -30		А
Maximum Power Dissipation	P _D	2.10 2.10		W
Junction Temperature	TJ	150		°C
Storage Temperature Range	T _{STG}	-55 to +150		°C

Thermal Characteristics

Thermal Resistance Junction-to-Ambient Note2	Pau	62.5	°C/W
Thermal Resistance, Junction-to-Ambient Note2	Reja	02.5	1 C/VV

N-Channel

Electrical Characteristics

(T_a=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μ A	30	33	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V,V _{GS} =0V		-	1	μΑ
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} = 0 V		-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1	1.6	3	V
Davis Course On Otata Basistana	Б	V _{GS} =10V, I _D =6A	-	19	31	- mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =6A	-	26	40	
Forward Transconductance	g FS	V_{DS} =5 V , I_{D} =6 A		-	-	S
Dynamic Characteristics (Note4)						•
Input Capacitance	C _{lss}	V _{DS} =15V,V _{GS} =0V, F=1.0MHz	-	530.3	-	PF
Output Capacitance	C _{oss}		-	67.1	-	PF
Reverse Transfer Capacitance	C _{rss}		-	61.2	-	PF
Switching Characteristics (Note 4)	<u> </u>		•			
Turn-on Delay Time	t _{d(on)}		-	4.5	-	nS
Turn-on Rise Time	t _r	V_{DD} =15V, R_L =2.5 Ω	-	2.5	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10 V , R_{GEN} =3 Ω	-	14.5	-	nS
Turn-Off Fall Time	t _f		-	3.5	-	nS
Total Gate Charge	Qg	V _{DS} =15V,I _D =6A, V _{GS} =10V	-	14.2	-	nC
Gate-Source Charge	Q _{gs}		-	1.8	-	nC
Gate-Drain Charge	Q_gd		-	3.3	-	nC
Drain-Source Diode Characteristics			•	•		•
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =6A	-	0.8	1.2	V

P-Channel

Electrical Characteristics

(T_a=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250μ A		-33	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V,V _{GS} = 0 V		-	-1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V		-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} ,I _D =-250μ A	-	-1.	-2.0	V
	В	V _{GS} =-10V, I _D =-6.5A		54	60	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-4.5V, I _D =-5A		64	87	
Forward Transconductance	g fs	V_{DS} =-5 V , I_{D} =-6.5 A		-	-	S
Dynamic Characteristics (Note4)				•		•
Input Capacitance	C _{lss}	V _{DS} =-15V,V _{GS} =0V, F=1.0MHz	-	956.1	-	PF
Output Capacitance	C _{oss}		-	122	-	PF
Reverse Transfer Capacitance	C _{rss}		-	116.2	-	PF
Switching Characteristics (Note 4)			•			
Turn-on Delay Time	t _{d(on)}		-	8	-	nS
Turn-on Rise Time	t _r	V_{DD} =-15V, R_L =2.3 Ω		6	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =-10 V , R_{GEN} =6 Ω	-	20	-	nS
Turn-Off Fall Time	t _f		-	7.5	-	nS
Total Gate Charge	Qg	\/ 45\/ 0.5A	-	21.3	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =-15V,I _D =-6.5A V _{GS} =-10V	-	2.2	-	nC
Gate-Drain Charge	Q_{gd}		-	4.5	-	nC
Drain-Source Diode Characteristics			•	•		
Diode Forward Voltage (Note 3)	V_{SD}	V _{GS} =0V,I _S =-6.5A		-	-1.2	V

Notes:

- $\textbf{1.} \ \textbf{Repetitive Rating: Pulse width limited by maximum junction temperature.}$
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- 3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production

N-Channel

Typical Characteristics Curves

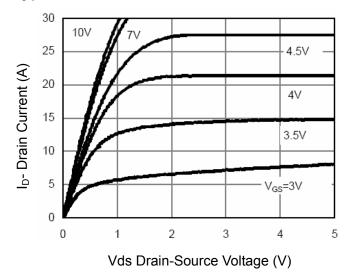


Figure 1 Output Characteristics

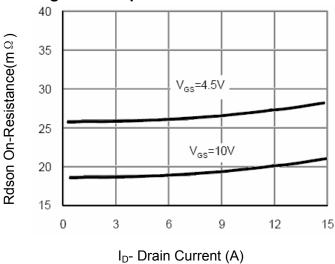


Figure 3 Drain-Source On-Resistance

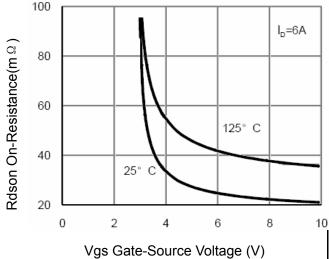


Figure 5 Rdson vs Vgs

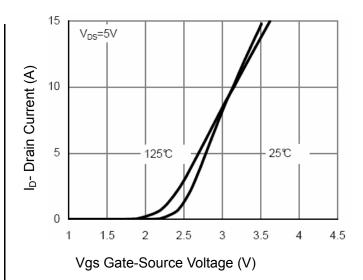


Figure 2 Transfer Characteristics

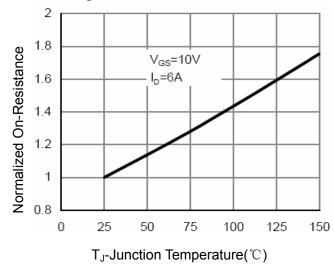
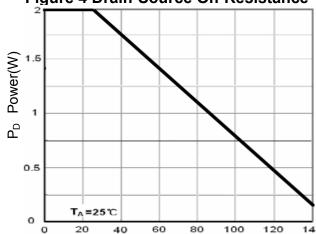
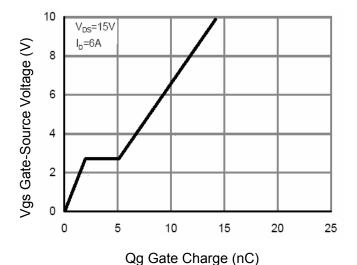


Figure 4 Drain-Source On-Resistance



 T_J -Junction Temperature(${}^{\circ}\mathbb{C}$)

Figure 6 Power Dissipation



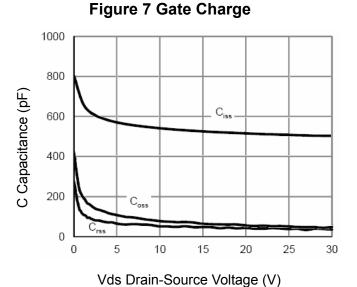


Figure 9 Capacitance vs Vds

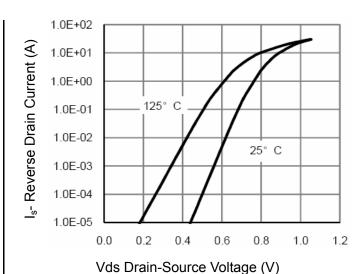
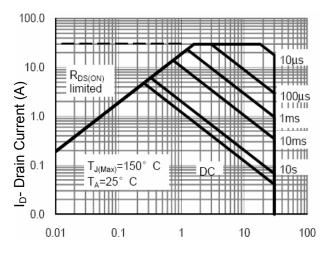


Figure 8 Source- Drain Diode Forward



Vds Drain-Source Voltage (V)
Figure 10 Safe Operation Area

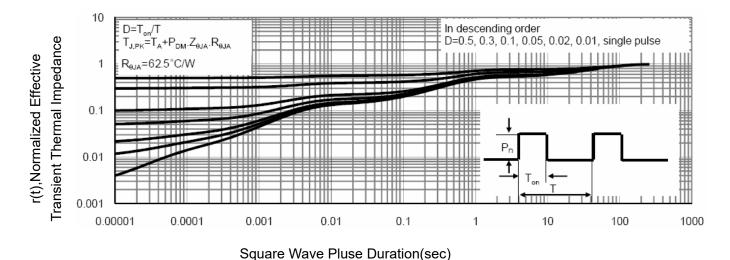


Figure 11 Normalized Maximum Transient Thermal Impedance

P-Channel

Typical Characteristics Curves

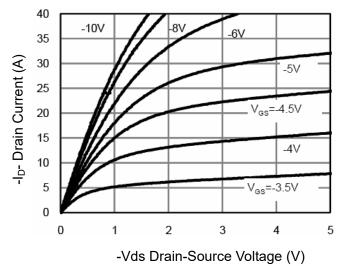


Figure 1 Output Characteristics

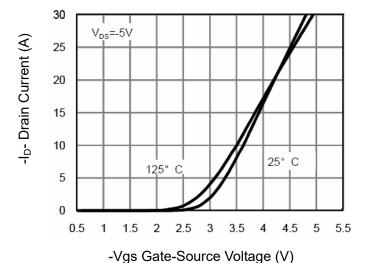


Figure 2 Transfer Characteristics

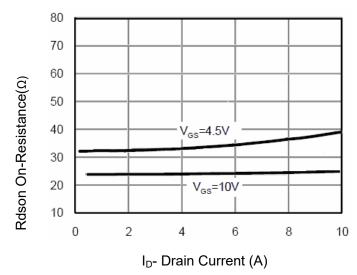


Figure 3 Rdson- Drain Current

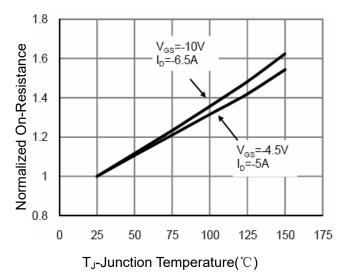


Figure 4 Rdson-Junction Temperature

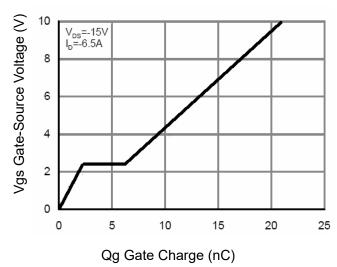


Figure 5 Gate Charge

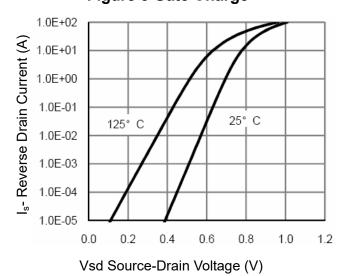


Figure 6 Source- Drain Diode Forward

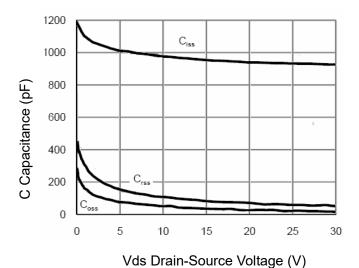
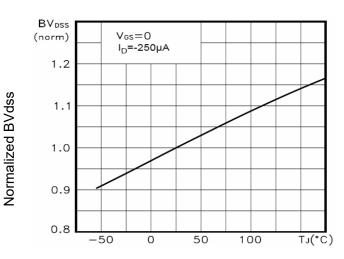


Figure 7 Capacitance vs Vds



 $\mathsf{T}_{\mathsf{J}} ext{-Junction Temperature}(^{\circ}\!\mathbb{C})$

Figure 9 BV_{DSS} vs Junction Temperature

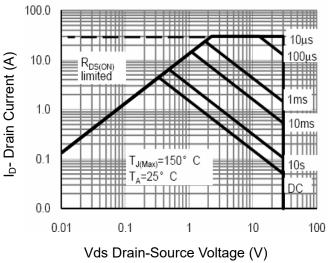


Figure 8 Safe Operation Area

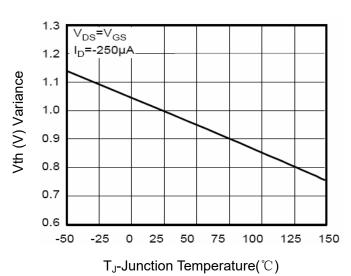


Figure 10 V_{GS(th)} vs Junction Temperature

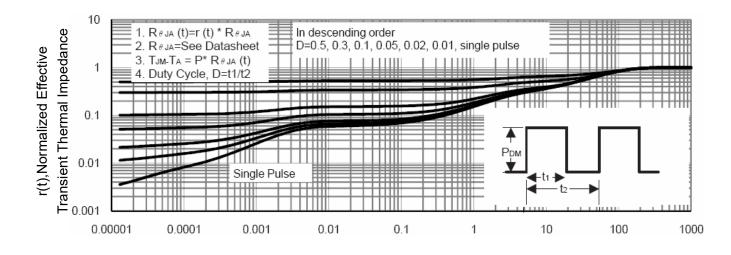


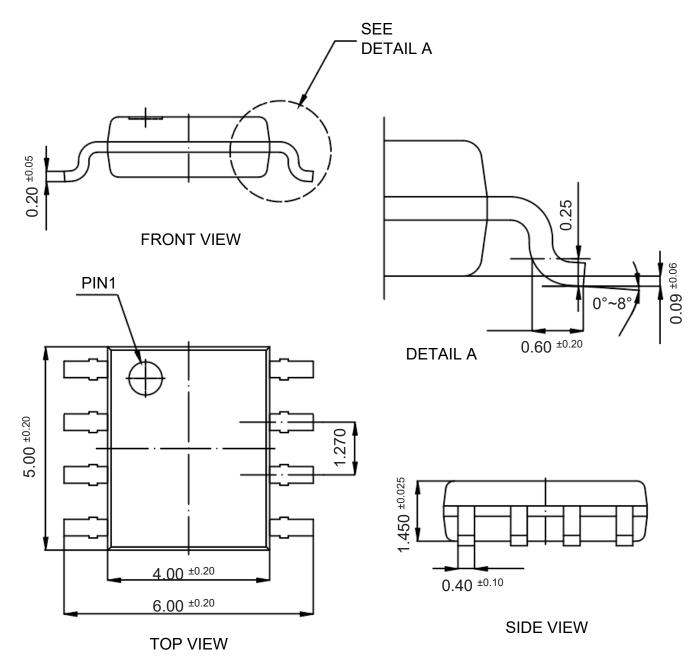
Figure 11 Normalized Maximum Transient Thermal Impedance

Square Wave Pluse Duration(sec)

Package Outline

SOP-8

Dimensions in mm

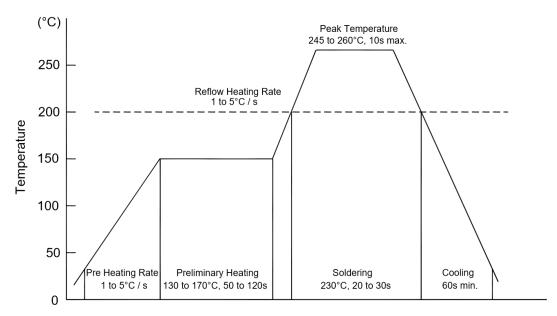


Ordering Information

Device	Package	Shipping
TN08C30JPA	SOP-8	4,000PCS/Reel&13inches

Conditions of Soldering and Storage

Recommended condition of reflow soldering



Recommended peak temperature is over 245°C. If peak temperature is below 245°C, you may adjust the following parameters:

- Time length of peak temperature (longer)
- Time length of soldering (longer)
- Thickness of solder paste (thicker)

Conditions of hand soldering

Temperature: 300°C

Time: 3s max.Times: one time

♦ Storage conditions

Temperature

5 to 40°C

Humidity

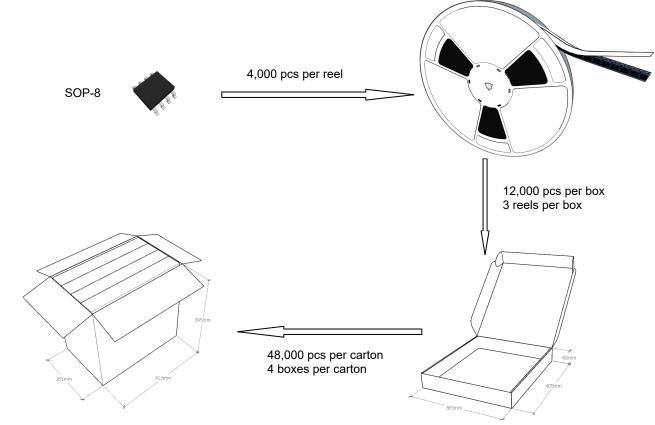
30 to 80% RH

Recommended period

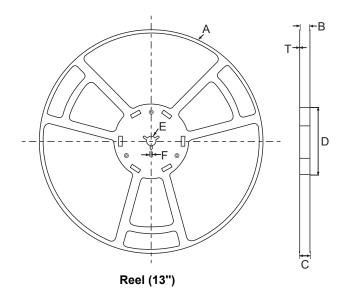
One year after manufacturing

Package Specifications

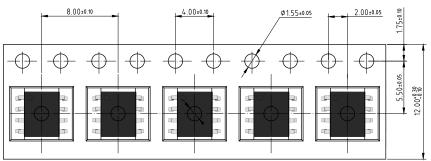
• The method of packaging



♦ Embossed tape and reel data



symbol	Value(unit:mm)
А	φ 330±1
В	12.7±0.5
С	16.5±0.3
D	ф 99.5±0.5
Е	ф 13.6±0.3
F	2.8±0.3
Т	1.9±0.2



Contact Information

For additional information, please contact your local Sales Representative.



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Product Specification Statement

The product specification aims to provide users with a reference regarding various product parameters, performance, and usage. It presents certain aspects of the product's performance in graphical form and is intended solely for users to select product and make product comparisons, enabling users to better understand and evaluate the characteristics and advantages of the product. It does not constitute any commitment, warranty, or guarantee.

The product parameters described in the product specification are numerical values, characteristics, and functions obtained through actual testing or theoretical calculations of the product in an independent or ideal state. Due to the complexity of product applications and variations in test conditions and equipment, there may be slight fluctuations in parameter test values. TANI shall not guarantee that the actual performance of the product when installed in the customer's system or equipment will be entirely consistent with the product specification, especially concerning dynamic parameters. It is recommended that users consult with professionals for product selection and system design. Users should also thoroughly validate and assess whether the actual parameters and performance when installed in their respective systems or equipment meet their requirements or expectations. Additionally, users should exercise caution in verifying product compatibility issues, and TANI assumes no responsibility for the application of the product. TANI strives to provide accurate and up -to- date information to the best of our ability. However, due to technical, human, or other reasons, TANI cannot guarantee that the information provided in the product specification is entirely accurate and error-free. TANI shall not be held responsible for any losses or damages resulting from the use or reliance on any information in these product specifications.

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Users are advised to pay attention to the parameter limit values specified in the product specification and maintain a certain margin in design or application to ensure that the product does not exceed the parameter limit values defined in the product specification. This precaution should be taken to avoid exceeding one or more of the limit values, which may result in permanent irreversible damage to the product, ultimately affecting the quality and reliability of the system or equipment.

The design of the product is intended to meet civilian needs and is not guaranteed for use in harsh environments or precision equipment. It is not recommended for use in systems or equipment such as medical devices, aircraft, nuclear power, and similar systems, where failures in these systems or equipment could reasonably be expected to result in personal injury. TANI shall assume no responsibility for any consequences resulting from such usage.

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